

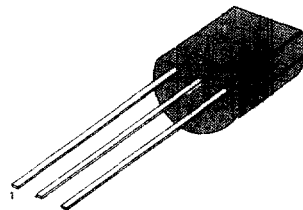
SWITCHING AND AMPLIFIER

- HIGH VOLTAGE: BC556, $V_{CE0} = -65V$
- LOW NOISE: BC559, BC560
- Complement to BC546 ... BC 550

ABSOLUTE MAXIMUM RATINGS ($T_A = 25^\circ C$)

Characteristic	Symbol	Rating	Unit
Collector-Base Capacitance	V_{CBO}		
:BC556		-80	V
:BC557/560		-50	V
:BC558/559		-30	V
Collector-Emitter Voltage	V_{CEO}		
:BC556		-65	V
:BC557/560		-45	V
:BC558/559		-30	V
Emitter-Base Voltage	V_{EBO}	-5	V
Collector Current (DC)	I_C	-100	mA
Collector Dissipation	P_C	500	mW
Junction Temperature	T_J	150	$^\circ C$
Storage Temperature	T_{STG}	-65 ~ 150	$^\circ C$

TO-92



1. Collector 2. Base 3. Emitter

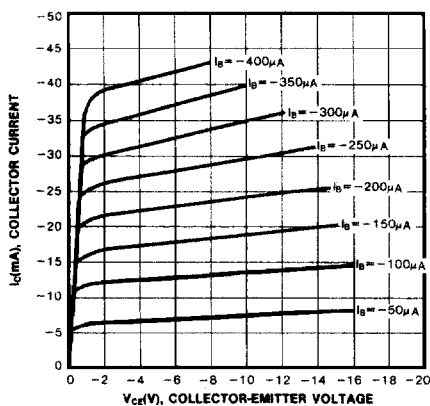
ELECTRICAL CHARACTERISTICS ($T_A = 25^\circ C$)

Characteristic	Symbol	Test Conditions	Min	Typ	Max	Unit
Collector Cut-off Current	I_{CBO}	$V_{CB} = -30V, I_E = 0$			-15	nA
DC Current Gain	h_{FE}	$V_{CE} = -5V, I_C = 2mA$	110		800	
Collector Emitter Saturation Voltage	$V_{CE(sat)}$	$I_C = -10mA, I_B = -0.5mA$		-90	-300	mV
		$I_C = -100mA, I_B = -5mA$		-250	-650	mV
Collector Base Saturation Voltage	$V_{BE(on)}$	$I_C = -10mA, I_B = -0.5mA$		-700		mV
		$I_C = -100mA, I_B = -5mA$		-900		mV
Base Emitter On Voltage	$V_{BE(on)}$	$V_{CE} = -5V, I_C = -2mA$	-600	-660	-750	mV
		$V_{CE} = -5V, I_C = -10mA$		-800		mV
Current Gain Bandwidth Product	f_T	$V_{CE} = -5V, I_C = -10mA$		150		MHz
Collector Base Capacitance	C_{CBO}	$V_{CB} = -10V, f = 1MHz$			6	pF
Noise Figure :BC556/557/558	NF	$V_{CE} = -5V, I_C = -200\mu A$		2	10	dB
:BC559/560		$f = 1KHz, R_G = 2k\Omega$		1	4	dB
:BC559	NF	$V_{CE} = -5V, I_C = -200\mu A$		1.2	4	dB
:BC560		$R_G = 2k\Omega$		1.2	2	dB
		$f = 30 \sim 15000MHz$				

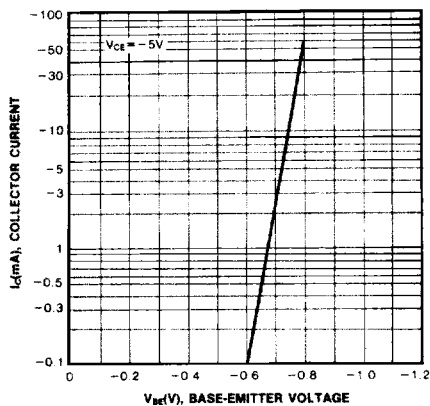
 h_{FE} CLASSIFICATION

Classification	A	B	C
h_{FE}	110-220	200-450	420-800

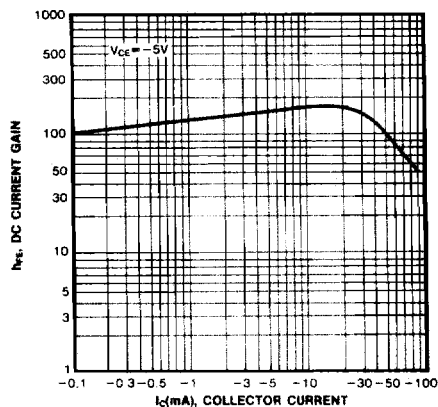
STATIC CHARACTERISTIC



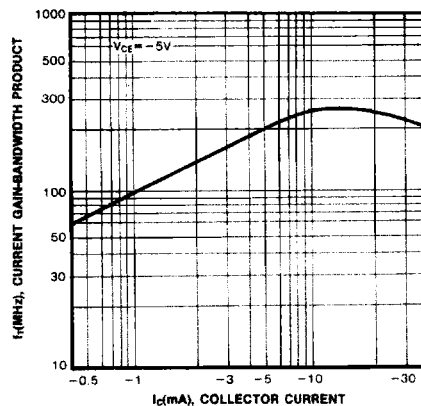
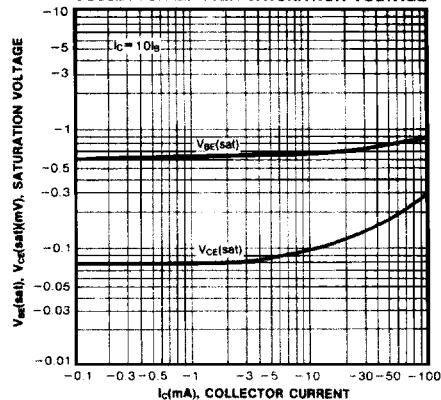
BASE-EMITTER VOLTAGE



DC CURRENT GAIN



CURRENT GAIN-BANDWIDTH PRODUCT

BASE-EMITTER SATURATION VOLTAGE
COLLECTOR-EMITTER SATURATION VOLTAGE

COLLECTOR OUTPUT CAPACITANCE

